Vishay Semiconductors

High Performance Schottky Rectifier, 2.1 A

Anode

-0



www.vishay.com

SMA

| PRODUCT SUMMARY | | | | | |
|----------------------------------|-----------------|--|--|--|--|
| Package | SMA | | | | |
| I _{F(AV)} | 2.1 A | | | | |
| V _R | 40 V | | | | |
| V _F at I _F | 0.54 V | | | | |
| I _{RM} | 26 mA at 125 °C | | | | |
| T _J max. | 150 °C | | | | |
| Diode variation | Single die | | | | |
| E _{AS} | 3.0 mJ | | | | |

FEATURES

- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-10MQ040NPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | |
|-----------------------------------|---|------------------------------|----|--|--|--|
| SYMBOL | CHARACTERISTICS | CHARACTERISTICS VALUES UNITS | | | | |
| I _{F(AV)} | DC | 2.1 | A | | | |
| V _{RRM} | | 40 | V | | | |
| I _{FSM} | t _p = 5 μs sine | 120 | А | | | |
| V _F | 1.5 A _{pk} , T _J = 125 °C | 0.56 | V | | | |
| TJ | Range | -55 to +150 | °C | | | |

| VOLTAGE RATINGS | | | | | | |
|--------------------------------------|------------------|----------------|-------|--|--|--|
| PARAMETER | SYMBOL | VS-10MQ040NPbF | UNITS | | | |
| Maximum DC reverse voltage | V _R | 40 | V | | | |
| Maximum working peak reverse voltage | V _{RWM} | 40 | v | | | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|---|--------------------|---|---|-----|----|--|
| PARAMETER | SYMBOL | TEST CONDIT | TEST CONDITIONS | | | |
| Maximum average forward current See fig. 4 | I _{F(AV)} | 50 % duty cycle at T_L = 123 °C, rectangular waveform On PC board 9 mm ² island (0.013 mm thick copper pad area) | | 2.1 | А | |
| Maximum peak one cycle | 1 | 5 µs sine or 3 µs rect. pulse | Following any rated load condition and with | 120 | А | |
| non-repetitive surge current I _{FSM} See fig. 6 | | 10 ms sine or 6 ms rect. pulse | rated V _{RRM} applied | 30 | ~ | |
| Non-repetitive avalanche energy | E _{AS} | $T_J = 25 \text{ °C}, I_{AS} = 1 \text{ A}, L = 6 \text{ mH}$ | | 3.0 | mJ | |
| Repetitive avalanche current | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical 1.0 | | 1.0 | А | |

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COMPLIANT



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| ELECTRICAL SPECIFICATIONS | | | | | | |
|---|--------------------------------|--|---------------------------------|-------|------|--|
| PARAMETER | SYMBOL | TEST CO | VALUES | UNITS | | |
| Maximum forward voltage drop See fig. 1 | | 1 A | T.I = 25 °C | 0.54 | V | |
| | V _{FM} ⁽¹⁾ | 1.5 A | 1j=25 C | 0.62 | | |
| | V FM (") | 1 A | T _J = 125 °C | 0.49 | | |
| | | 1.5 A | 1j=125 C | 0.56 | | |
| Maximum reverse leakage current See fig. 2 | I _{RM} ⁽¹⁾ | T _J = 25 °C | $V_{\rm B}$ = Rated $V_{\rm B}$ | 0.5 | mA | |
| | | T _J = 125 °C | $v_{\rm R} = naleu v_{\rm R}$ | 26 | | |
| Threshold voltage | V _{F(TO)} | | 0.36 | V | | |
| Forward slope resistance | r _t | $T_J = T_J maximum$ 104 | | 104 | mΩ | |
| Typical junction capacitance | CT | $V_R = 10 V_{DC}, T_J = 25 \text{ °C}, \text{ test signal} = 1 \text{ MHz}$ 38 | | 38 | pF | |
| Typical series inductance | L _S | Measured lead to lead 5 mm from package body 2.0 r | | nH | | |
| Maximum voltage rate of change | dV/dt | Rated V _R 10 000 V/µs | | | V/µs | |

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | |
|---|------------------------------------|-------------------------------|-------------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Maximum junction and storage temperature range | T_{J} ⁽¹⁾ , T_{Stg} | | -55 to +150 | °C | |
| Maximum thermal resistance, junction to ambient | R _{thJA} | DC operation | 80 | °C/W | |
| | | | 0.07 | g | |
| Approximate weight | | | 0.002 | oz. | |
| Marking device | | Case style SMA (similar D-64) | V | IF | |

Note

⁽¹⁾ $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

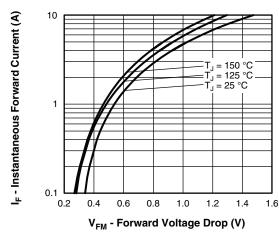


Fig. 1 - Maximum Forward Voltage Drop Characteristics

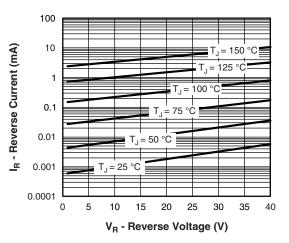


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

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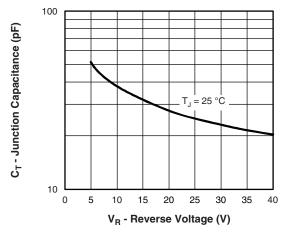


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

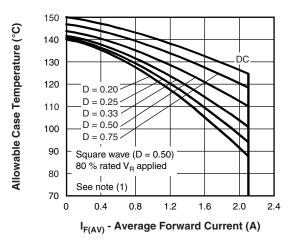


Fig. 4 - Maximum Average Forward Current vs. Allowable Lead Temperature

Note



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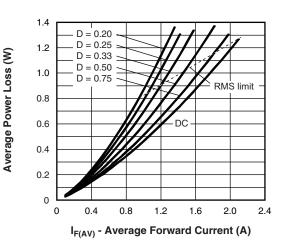


Fig. 5 - Maximum Average Forward Dissipation vs. Average Forward Current

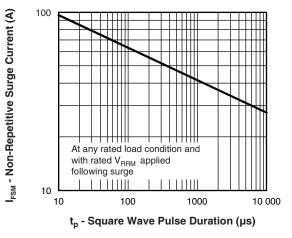


Fig. 6 - Maximum Peak Surge Forward Current vs. **Pulse Duration**

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ORDERING INFORMATION TABLE

| Device code | VS- | 10 | М | Q | 040 | N | TR | PbF |
|-------------|-----|------|-----------|-----------|-----------|--------|----|-----|
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 |
| | 1 - | Visl | nay Sem | niconduc | ctors pro | oduct | | |
| | 2 - | Cur | rent rati | ng | | | | |
| | 3 - | M = | SMA | | | | | |
| | 4 - | Q = | Schottk | ky "Q" se | eries | | | |
| | 5 - | Volt | age rati | ng (040 | = 40 V) | | | |
| | 6 - | N = | new SN | ΛA | | | | |
| | 7 - | • N | one = bo | ox (1000 |) pieces |) | | |
| | | • TI | R = tape | and ree | el (7500 | pieces |) | |
| | 8 - | PbF | = lead | (Pb)-fre | е | | | |

| LINKS TO RELATED DOCUMENTS | | | | | |
|-------------------------------------|---------------|--------------------------|--|--|--|
| Dimensions www.vishay.com/doc?95018 | | | | | |
| Part marking information | | www.vishay.com/doc?95029 | | | |
| Packaging information | Tape and reel | www.vishay.com/doc?95034 | | | |
| Packaging information | Bulk | www.vishay.com/doc?95397 | | | |
| SPICE model | | www.vishay.com/doc?95277 | | | |

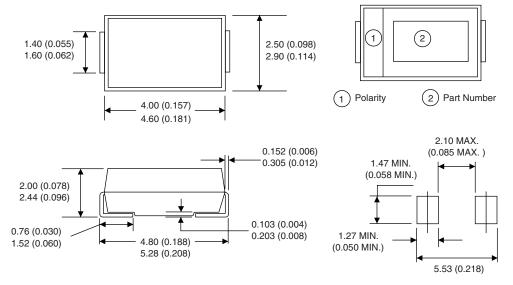


Outline Dimensions

Vishay High Power Products

SMA

DIMENSIONS in millimeters (inches)



Soldering pad



Vishay

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